

UNISONIC TECHNOLOGIES CO., LTD

80N07

Preliminary

80A, 70V N-CHANNEL **POWER MOSFET**

DESCRIPTION

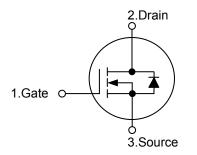
The UTC 80N07 is an N-channel MOSFET using UTC advanced technology.

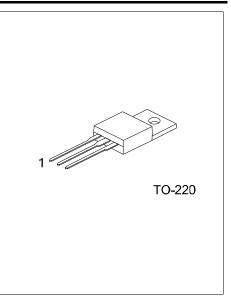
The UTC 80N07 is suitable for power supply (secondary synchronous rectification), industrial and primary switch etc.

FEATURES

* $R_{DS(ON)}$ < 15m Ω @ V_{GS} = 10 V, I_D = 40 A

SYMBOL





ORDERING INFORMATION

Ordering Number		Deekege	Pin Assignment			Deaking
Lead Free	Halogen Free	Package	1	2	3	Packing
80N07L-TA3-T	80N07G-TA3-T	TO-220	G	D	S	Tube
Note: Pin Assignment: G: Gate D: Drain S: Source						

80N07L-TA3-T	(1) T: Tube
(2)Package Type	(2) TA3: TO-220
(3)Green Package	(3) L: Lead Free, G: Halogen Free and Lead Free

MARKING



ABSOLUTE MAXIMUM RATINGS (Tc=25°C, unless otherwise specified)

PARAMETER		SYMBOL	RATINGS	UNIT
Drain-Source Voltage		V _{DSS}	70	V
Gate-Source Voltage		V _{GSS}	±20	V
Continuous Drain Current	Continuous	I _D	80	А
Pulsed Drain Current	Pulsed (Note 2)	I _{DM}	320	А
Avalanche Current (Note 3)		I _{AR}	10	А
Avalanche energy	Single Pulsed (Note 3)	E _{AS}	5.0	mJ
Peak Diode Recovery dv/dt (Note 4)		dv/dt	5.5	V/nS
Power Dissipation		PD	230	W
Junction Temperature		TJ	+150	°C
Storage Temperature Range		T _{STG}	-55 ~ +150	°C

Notes: 1. Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

2. Repetitive Rating: Pulse width limited by maximum junction temperature.

3. L=0.1mH, I_{AS} =10A, V_{DD} =50V, R_G =25 Ω , Starting T_J = 25°C.

4. $I_{SD} \leq 30A$, di/dt $\leq 200A/\mu s$, $V_{DD} \leq V_{(BR)DSS}$, $T_J = 25^{\circ}C$.

THERMAL DATA

PARAMETER	SYMBOL	RATINGS	UNIT	
Junction to Ambient	θ _{JA}	62.5	°C/W	
Junction to Case	$\theta_{\rm JC}$	0.54	°C/W	

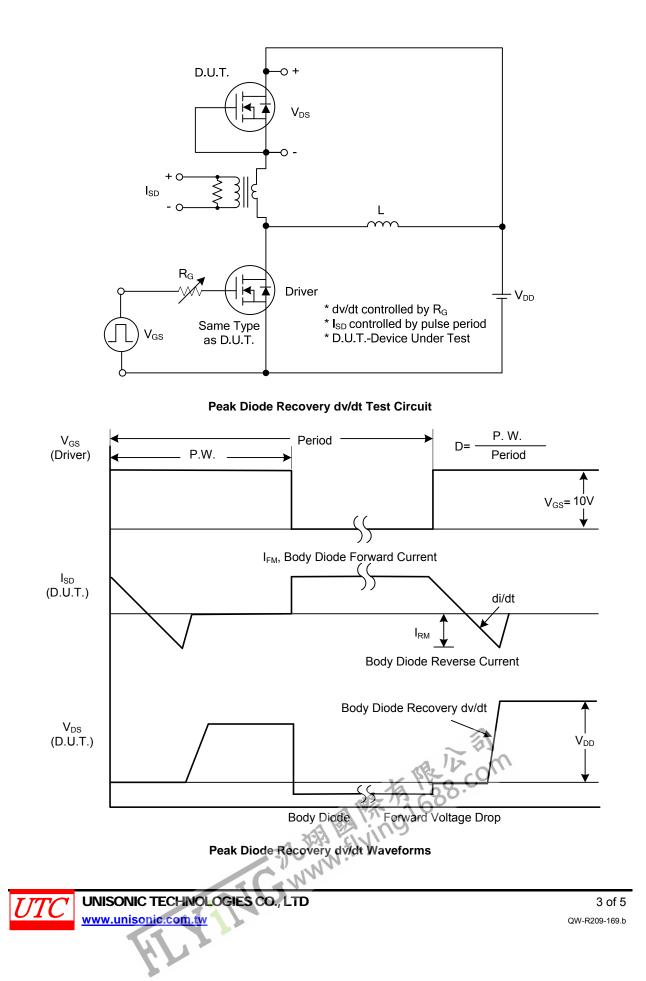
ELECTRICAL CHARACTERISTICS (T_J =25°C, unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
OFF CHARACTERISTICS						
Drain-Source Breakdown Voltage	BV _{DSS}	I _D =250μA, V _{GS} =0V				V
Drain-Source Leakage Current	I _{DSS}	V _{DS} =70V, V _{GS} =0V			1	μA
Gate-Source Leakage Current	I _{GSS}	V_{DS} =0V, V_{GS} =±20V			±100	nA
ON CHARACTERISTICS						
Gate Threshold Voltage	V _{GS(TH)}	V _{DS} =V _{GS} , I _D =250µA			4.0	V
Static Drain-Source On-State Resistance	R _{DS(ON)}	V _{GS} =10V, I _D =40A			15	mΩ
DYNAMIC PARAMETERS						
Input Capacitance	CISS			5480		рF
Output Capacitance	C _{OSS}	V _{GS} =0V, V _{DS} =25V, f=1.0MHz		405		рF
Reverse Transfer Capacitance	C _{RSS}			313		pF
SWITCHING PARAMETERS						
Total Gate Charge (Note 1)	Q_{G}	-V _{DS} =50V, V _{GS} =10V, I _D =1.3A, - -I _D =100μA (Note 1, 2)		390		nC
Gate to Source Charge	Q_{GS}			64		nC
Gate to Drain Charge	Q_{GD}			90		nC
Turn-on Delay Time (Note 1)	t _{D(ON)}	V _{DS} =30V, V _{GS} =10V, I _D =0.5A,		334		ns
Rise Time	t _R			415		ns
Turn-off Delay Time	t _{D(OFF)}	R _G =25Ω (Note 1, 2)		880		ns
Fall-Time	t⊨			370		ns
SOURCE- DRAIN DIODE RATINGS AND CH	ARACTERIS	TICS				
Maximum Body-Diode Continuous Current	ls		~		80	Α
Maximum Body-Diode Pulsed Current	I _{SM}	I _S =80A, V ₆ s=0V			320	Α
Drain-Source Diode Forward Voltage (Note 1)	V _{SD}				1.2	V
Reverse Recovery Time (Note 1)	t _{rr}	I _S =30A, V _{GS} =0V,		60		ns
Reverse Recovery Charge	Q _{rr}	dl _⊭ /dt=100A/µs		70		nC
Notes: 1. Pulse Test : Pulse width ≤ 300µs, Du	ty cycle ≤ 2%					
2. Essentially independent of operating						

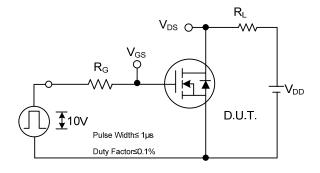
2. Essentially independent of operating temperature.

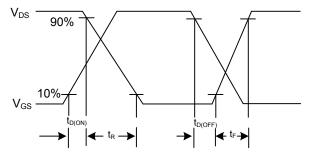


TEST CIRCUITS AND WAVEFORMS



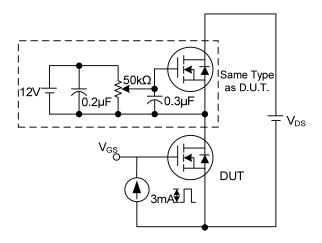
TEST CIRCUITS AND WAVEFORMS (Cont.)

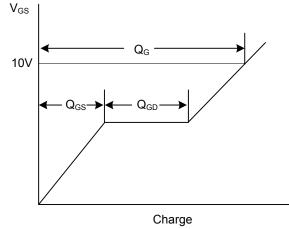




Switching Test Circuit

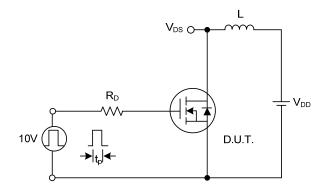






Gate Charge Test Circuit

Gate Charge Waveform



 $\mathsf{BV}_{\mathsf{DSS}}$ I_{AS} I_{D(t)} $V_{\text{DS}(t)}$ V_{DD} t Unclamped Inductive Switching Waveforms

Unclamped Inductive Switching Test Circuit



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